



**DC COMPONENTS CO., LTD.**  
RECTIFIER SPECIALISTS

**MMB1505  
THRU  
MMB1510**

**TECHNICAL SPECIFICATIONS OF SINGLE-PHASE SILICON BRIDGE RECTIFIER**  
**VOLTAGE RANGE - 50 to 1000 Volts**      **CURRENT - 15 Amperes**

**FEATURES**

- \* Metal case for Maximum Heat Dissipation
- \* Diffused Junction
- \* High current capability
- \* Surge overload ratings - 300 Amperes
- \* Low forward voltage drop
- \* High Reliability

**MECHANICAL DATA**

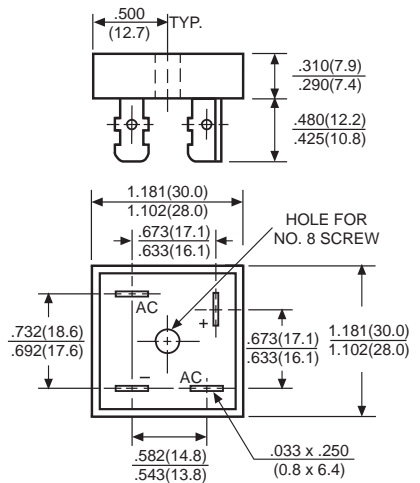
- \* Case: Metal case, electrically isolated
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Terminals: Plated .25"(6.35mm) Faston lugs, Solderable per MIL-STD-202E, Method 208 guaranteed
- \* Polarity: As marked
- \* Mounting position: Any
- \* Weight: 25 grams approx.

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Ratings at 25 °C ambient temperature unless otherwise specified.  
Single phase, half wave, 60 Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.



**MMB-25**



Dimensions in inches and (millimeters)

	SYMBOL	MMB1505	MMB151	MMB152	MMB154	MMB156	MMB158	MMB1510	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage	VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Output Current at Tc = 55°C	Io	15							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	300							Amps
Maximum Forward Voltage Drop per element at 7.5A DC	Vf	1.1							Volts
Maximum DC Reverse Current at Rated	IR	@TA = 25°C							μAmps
DC Blocking Voltage per element		@TA = 100°C							
I <sup>2</sup> t Rating for Fusing (t<8.3ms)	I <sup>2</sup> t	374							A <sup>2</sup> Sec
Typical Junction Capacitance (Note1)	Cj	40							pF
Typical Thermal Resistance (Note 2)	RθJA	19							°C/W
Operating and Storage Temperature Range	TJ,TSTG	-55 to +150							°C

NOTES : 1.Measured at 1 MHz and applied reverse voltage of 4.0 volts  
2.Thermal Resistance from Junction to Ambient and from Junction to Lead mounted on P.C.B. with 0.47 x 0.47" (12 x 12mm) copper pads.

# RATING AND CHARACTERISTIC CURVES (MMB1505 THRU MMB1510)

FIG. 1 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

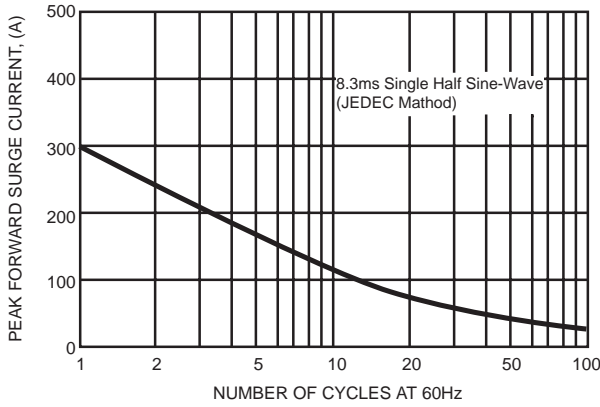


FIG. 2 - TYPICAL FORWARD CURRENT DERATING CURVE

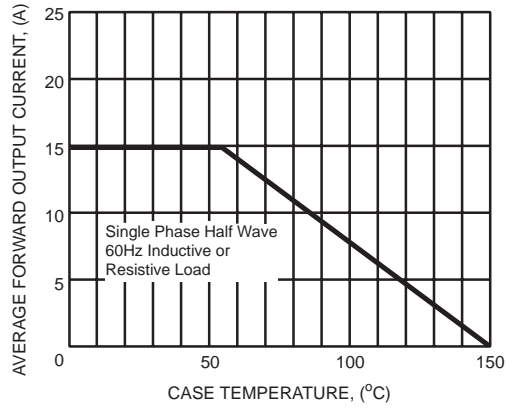


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

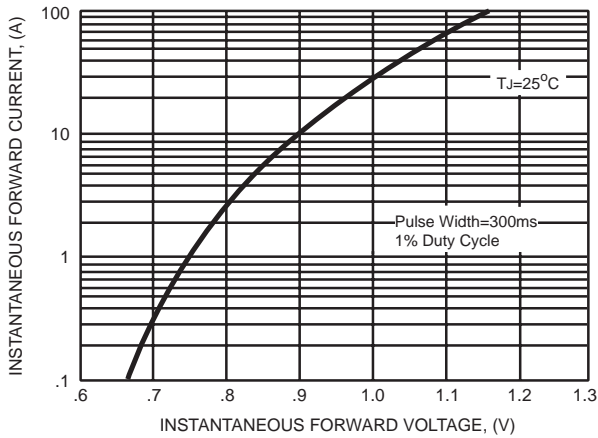
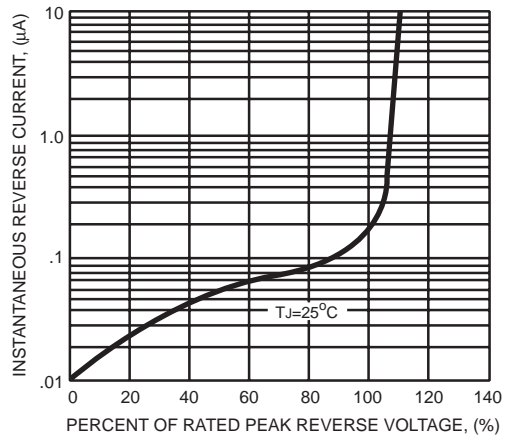


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS





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VOLTAGE RANGE - 50 to 1000 Volts  
CURRENT - 15 Amperes

FEATURES

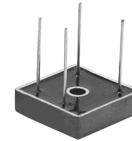
- \* Metal case for Maximum Heat Dissipation
- \* Diffused Junction
- \* High current capability
- \* Surge overload ratings - 300 Amperes
- \* Low forward voltage drop
- \* High Reliability

MECHANICAL DATA

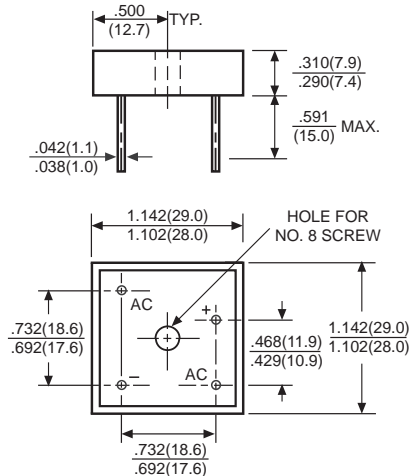
- \* Case: Metal case, electrically isolated
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Lead: MIL-STD-202E, Method 208 guaranteed
- \* Polarity: As marked
- \* Mounting position: Any
- \* Weight: 25 grams approx.

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.  
Single phase, half wave, 60 Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.



MMB-25W



Dimensions in inches and (millimeters)

	SYMBOL	MMB 1505W	MMB 151W	MMB 152W	MMB 154W	MMB 156W	MMB 158W	MMB 1510W	UNITS
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Output Current at T <sub>c</sub> = 55°C	I <sub>O</sub>	15							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	300							Amps
Maximum Forward Voltage Drop per element at 7.5A DC	V <sub>F</sub>	1.1							Volts
Maximum DC Reverse Current at Rated	I <sub>R</sub>	@ T <sub>A</sub> = 25°C							μAmps
DC Blocking Voltage per element		@ T <sub>A</sub> = 100°C							
I <sup>2</sup> t Rating for Fusing (t<8.3ms)	I <sup>2</sup> t	374							A <sup>2</sup> Sec
Typical Junction Capacitance (Note1)	C <sub>J</sub>	300							pF
Typical Thermal Resistance (Note 2)	R <sub>θJC</sub>	2.5							°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150							°C

NOTES : 1. Measured at 1 MHz and applied reverse voltage of 4.0 volts  
2. Thermal Resistance from Junction to Case per leg.

# RATING AND CHARACTERISTIC CURVES (MMB1505W THRU MMB1510W)

FIG. 1 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

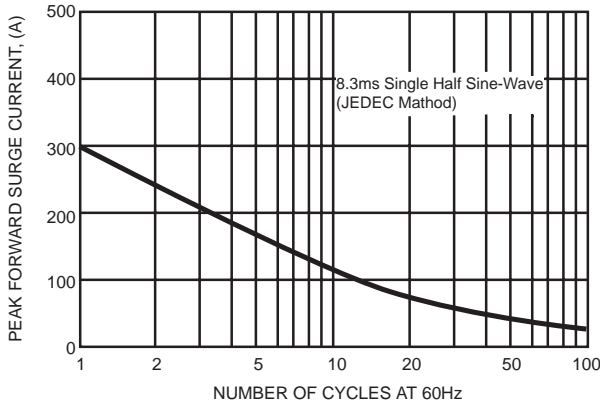


FIG. 2 - TYPICAL FORWARD CURRENT DERATING CURVE

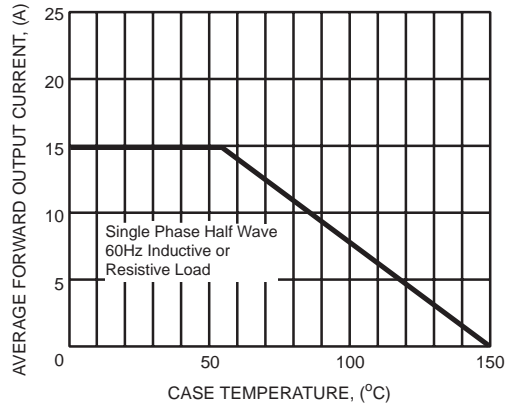


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

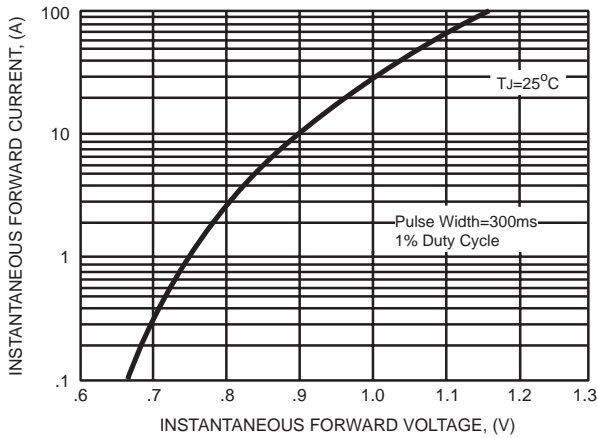


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

